Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-480-6132

Inclosure Material:

Ceramic

Overall Length:

10.540 millimeters

Overall Height:

29.330 millimeters

Overall Width:

2.890 millimeters

End Application:

Stv camera sy

Mounting Facility Quantity:

3

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

45.0 working peak reverse voltage

Current Rating Per Characteristic:

40.00 amperes forward current, average and 20.00 amperes operating voltage dc and 1240.00 amperes forward current, average pascal

and 350.00 amperes operating voltage dc pascal

Capacitance Rating In Picofarads:

2800.0

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction and -55.0 degrees celsius junction

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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